CMOS Digital Integrated Circuits Silicon Monolithic

74VHC574FT

1. Functional Description

• Octal D-Type Flip Flop with 3-State Outputs

2. General

The 74VHC574FT is an advanced high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}) .

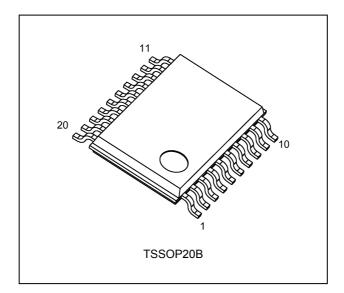
When the $\overline{\text{OE}}$ input is high, the eight outputs are in a high impedance state.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

- (1) High speed: f_{MAX} = 180 MHz (typ.) at V_{CC} = 5 V
- (2) Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_a = 25^{\circ}C$
- (3) High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- (4) Power-down protection is provided on all inputs.
- (5) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (6) Wide operating voltage range: $V_{CC(opr)} = 2 V \text{ to } 5.5 V$
- (7) Low noise: $V_{OLP} = 1.0 V (max)$
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 574 type.

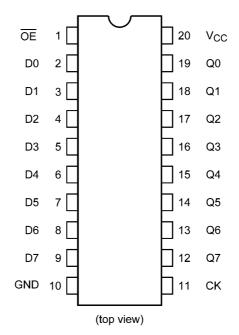
4. Packaging



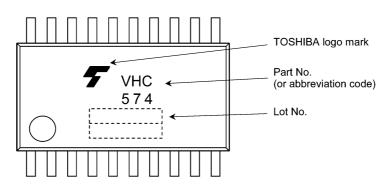
74VHC574FT

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5. Pin Assignment



6. Marking



7. IEC Logic Symbol

0E <u>(1)</u> CK <u>(11)</u>	EN > C1		
D0 (2) D1 (3) D2 (4) D3 (5) D4 (6) D5 (7) D6 (8) D7 (9)	1D		(19) Q0 (18) Q1 (17) Q2 (16) Q3 (15) Q4 (14) Q5 (13) Q6 (12) Q7

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8. Truth Table

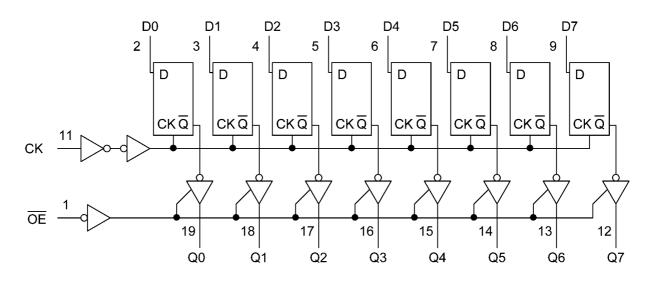
	Inputs	Output	
ŌĒ	СК	D	Output
н	Х	Х	Z
L		Х	Q _n
L		L	L
L		н	н

X: Don't care

Z: High impedance

Qn: No change

9. System Diagram



10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	-0.5 to 7.0	V
Input voltage	V _{IN}	-0.5 to 7.0	V
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	Ι _{ΟΚ}	±20	mA
Output current	I _{OUT}	±25	mA
V _{CC} /ground current	I _{CC}	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65 to 150	C°

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}		0 to V_{CC}	V
Operating temperature	T _{opr}		-40 to 85	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V	0 to 100	ns/V
		V_{CC} = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND.

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12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	_	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	—	
Low-level input voltage	VIL	—		2.0	_		0.50	V
				3.0 to 5.5			$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	2.0	—	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	—	
			I _{OH} = -4 mA	3.0	2.58		—	
			I _{OH} = -8 mA	4.5	3.94		—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I _{OL} = 4 mA	3.0	_		0.36	
			I _{OL} = 8 mA	4.5	_		0.36	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		5.5	_		±0.25	μΑ
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		_	±0.1	
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	

12.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition	1	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	—		2.0	1.50	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	—	
Low-level input voltage	VIL	—		2.0	—	0.50	V
				3.0 to 5.5	—	$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	2.0	1.9	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I _{OH} = -4 mA	3.0	2.48	—	
			I _{OH} = -8 mA	4.5	3.80	—	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 50 μA	2.0	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			I _{OL} = 4 mA	3.0	—	0.44	
			I _{OL} = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	—	±2.50	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±1.0	
Quiescent supply current	I _{CC}	V_{IN} = V_{CC} or GND		5.5	_	40.0	

12.3. Timing Requirements (Unless otherwise specified, $T_a = 25^{\circ}C$, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	V _{CC} (V)	Тур.	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	$\textbf{3.3}\pm\textbf{0.3}$		5.0	ns
(CK)		5.0 ± 0.5	_	5.0	ns
Minimum setup time	t _S	$\textbf{3.3}\pm\textbf{0.3}$	_	3.5	ns
		5.0 ± 0.5	_	3.5	ns
Minimum hold time	t _h	$\textbf{3.3}\pm\textbf{0.3}$	_	1.5	ns
		5.0 ± 0.5	_	1.5	ns

12.4. Timing Requirements

(Unless otherwise specified, $T_a = -40$ to 85°C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V _{CC} (V)	Limit	Unit
Minimum pulse width	t _{w(L)} ,t _{w(H)}	$\textbf{3.3}\pm\textbf{0.3}$	5.0	ns
(CK)		5.0 ± 0.5	5.0	
Minimum setup time	ts	$\textbf{3.3}\pm\textbf{0.3}$	3.5	ns
		5.0 ± 0.5	3.5	
Minimum hold time	t _h	$\textbf{3.3}\pm\textbf{0.3}$	1.5	ns
		5.0 ± 0.5	1.5	

12.5. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		—	$\textbf{3.3}\pm\textbf{0.3}$	15	—	8.5	13.2	ns
(CK-Q)					50	—	11.0	16.7	
				5.0 ± 0.5	15	_	5.6	8.6	
					50	—	7.1	10.6	
3-state output enable time	t _{PZL} ,t _{PZH}		R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	15	—	8.2	12.8	ns
					50	_	10.7	16.3	
				5.0 ± 0.5	15	_	5.9	9.0	
					50	—	7.4	11.0	
3-state output disable time	t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	50	_	11.0	15.0	ns
				5.0 ± 0.5	50	_	7.1	10.1	
Maximum clock frequency	f _{MAX}		_	$\textbf{3.3}\pm\textbf{0.3}$	15	80	125	_	MHz
					50	50	75	—	
				5.0 ± 0.5	15	130	180	—	
					50	85	115	_	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	—	3.3 ± 0.3	50	_	_	1.5	ns
				5.0 ± 0.5	50	_	_	1.0	ns
Input capacitance	C _{IN}		_			_	4	10	pF
Output capacitance	C _{OUT}		—			_	6	—	pF
Power dissipation capacitance	C _{PD}	(Note 2)	_			_	28	_	pF

Note 1: Parameter guaranteed by design.

 $\mathbf{t}_{\mathsf{OSLH}} = |\mathbf{t}_{\mathsf{PLHm}} - \mathbf{t}_{\mathsf{PLHn}}|, \ \mathbf{t}_{\mathsf{OSHL}} = |\mathbf{t}_{\mathsf{PHLm}} - \mathbf{t}_{\mathsf{PHLn}}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8 \text{ (per F/F)}$

And the total C_{PD} when n pcs of F/F operate can be gained by the following equation.

 C_{PD} (total) = 20 + 8 × n

12.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition		C (nE)	Min	Max	Unit
Characteristics	Symbol	NOLE	Test Condition	V _{CC} (V)	C _L (pF)	IVIIII	IVIAX	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		—	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	15.5	ns
(CK-Q)					50	1.0	19.0	
				5.0 ± 0.5	15	1.0	10.0	
					50	1.0	12.0	
3-state output enable time	t _{PZL} ,t _{PZH}		R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	15.0	ns
					50	1.0	18.5	1
				5.0 ± 0.5	15	1.0	10.5	1
					50	1.0	12.5	
3-state output disable time	t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	17.0	ns
					15	1.0	11.5	1
Maximum clock frequency	f _{MAX}		_	$\textbf{3.3}\pm\textbf{0.3}$	15	65	_	MHz
					50	45	_	
				5.0 ± 0.5	15	110	_	
					50	75	—	
Output skew	t _{osLH} ,t _{osHL}	(Note 1)	_	3.3 ± 0.3	50	_	1.5	ns
				5.0 ± 0.5	50	_	1.0	ns
Input capacitance	CIN		_			_	10	pF

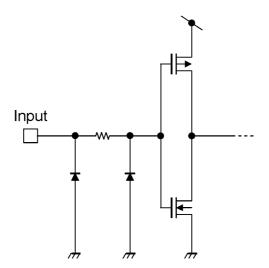
Note 1: Parameter guaranteed by design.

 $t_{osLH} = |t_{PLHm} - t_{PLHn}|, tosHL = |t_{PHLm} - t_{PHLn}|$

12.7. Noise Characteristics (Unless otherwise specified, $T_a = 25^{\circ}$ C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.8	1.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.8	-1.0	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0		3.5	
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	

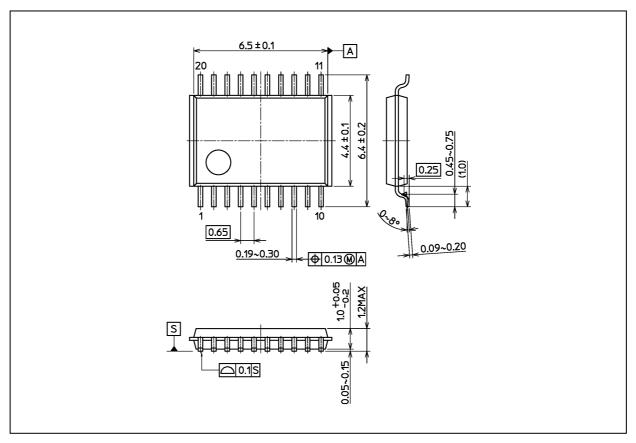
13. Input Equivalent Circuit





Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

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